

I acknowledge the duty to disclose information which is material to patentability as defined in Title 37, Code of Federal Regulations, Section 1.56.

Japanese Language Declaration (日本語宣言書)

私は、米国法典第 35 編 119 条(a)-(d)項又は 365 条(b)項に基き下記の、米国以外の国の少なくとも一カ国を指定している特許協力条約 365(a)項に基く国際出願、又は外国での特許出願もしくは発明者証の出願についての外国優先権をここに主張するとともに、優先権を主張している、本出願の前に出願された特許または発明者証の外国出願を以下に、枠内をマークすることで、示しています。

I hereby claim foreign priority under Title 35, United States Code, Section 119(a)-(d) or 365(b) of any foreign application(s) for patent or inventor's certificate, or 365(a) of any PCT International application which designated at least one country other than the United States, listed below and have also identified below, by checking the box, any foreign application for patent or inventor's certificate, or PCT International application having a filing date before that of the application on which priority is claimed.

Prior Foreign Application(s)

外国での先行出願

Priority Not Claimed

優先権主張なし

<u>2000-128526</u> (Number) (番号)	<u>Japan</u> (Country) (国名)	<u>April 27, 2000</u> (Day/Month/Year Filed) (出願年月日)	<input type="checkbox"/>
<u> </u> (Number) (番号)	<u> </u> (Country) (国名)	<u> </u> (Day/Month/Year Filed) (出願年月日)	<input type="checkbox"/>
<u> </u> (Number) (番号)	<u> </u> (Country) (国名)	<u> </u> (Day/Month/Year Filed) (出願年月日)	<input type="checkbox"/>

私は、第 35 編米国法典 119 条(e)項に基いて下記の米国特許出願規定に記載された権利をここに主張いたします。

I hereby claim the benefit under Title 35, United States Code, Section 119(e) of any United States provisional application(s) listed below.

<u> </u> (Application No.) (出願番号)	<u> </u> (Filing Date) (出願日)	<u> </u> (Application No.) (出願番号)	<u> </u> (Filing Date) (出願日)
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私は、下記の米国法典第 35 編 120 条に基いて下記の米国特許出願に記載された権利、又は米国を指定している特許協力条約 365 条(c)に基く権利をここに主張します。また、本出願の各請求範囲の内容が米国法典代 35 編 112 条第 1 項又は特許協力条約で規定された方法で先行する米国特許出願に開示されていない限り、その先行米国出願提出日以降で本出願書の日本国内または特許協力条約国際提出日までの期間中に入手された、連邦規制法典第 37 編 1 条 56 項で定義された特許資格の有無に関する重要な情報について開示義務があることを認識しています。

I hereby claim the benefit under Title 35, United States Code, Section 120 of any United States application(s), or 365(c) of any PCT International application designating the United States, listed below and, insofar as the subject matter of each of the claims of this application is not disclosed in the prior United States or PCT International application in the manner provided by the first paragraph of Title 35, United States Code Section 112, I acknowledge the duty to disclose information which is material to patentability as defined in Title 37, Code of Federal Regulations, Section 1.56 which became available between the filing date of the prior application and the national or PCT International filing date of application.

<u> </u> (Application No.) (出願番号)	<u> </u> (Filing Date) (出願日)	<u> </u> (Status: Patented, Pending, Abandoned) (現況: 特許許可済、継続中、放棄済)
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(Application No.) (出願番号)	(Filing Date) (出願日)	(Status: Patented, Pending, Abandoned) (現況: 特許許可済、継続中、放棄済)
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私は、私自身の知識に基づいて本宣言書中で私が行う表明が真実であり、かつ私の入手した情報と私の信じるに基く表明が全て真実であると信じていること、さらに故意になされた虚偽の表明及びそれと同等の行為は米国法典第 18 編第 1001 条に基づき、罰金または拘禁、もしくはその両方により処罰されること、そしてそのような故意による虚偽の声明を行えば、出願した、又は既に許可された特許の有効性が失われることを認識し、よってここに上記のごとく宣誓を致します。

I hereby declare that all statements made herein of my own knowledge are true and that all statements made on information and belief are believed to be true; and further that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment, or both, under Section 1001 of Title 18 of the United States Code and that such willful false statements may jeopardize the validity of the application or any patent issued thereon.

Variable	Unit	Value	Unit	Value
Mean age	yr	24.5	SD	3.5
Mean height	cm	170.5	SD	5.5
Mean weight	kg	65.5	SD	10.5
Mean BMI	kg/m ²	22.5	SD	3.5
Mean waist circumference	cm	85.5	SD	10.5
Mean systolic blood pressure	mmHg	115.5	SD	10.5
Mean diastolic blood pressure	mmHg	75.5	SD	8.5
Mean heart rate	beats/min	75.5	SD	10.5
Mean resting energy expenditure	kcal/day	2450	SD	300
Mean total energy expenditure	kcal/day	3200	SD	400
Mean fat mass	kg	12.5	SD	3.5
Mean lean mass	kg	53.0	SD	7.0
Mean bone mineral density	g/cm ²	1.05	SD	0.05
Mean bone mineral content	g	1200	SD	100
Mean bone mineral density (areal)	g/cm ²	1.05	SD	0.05
Mean bone mineral content (areal)	g	1200	SD	100
Mean bone mineral density (volumetric)	g/cm ³	1.05	SD	0.05
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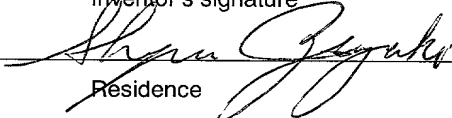
POWER OF ATTORNEY: As a named inventor, I hereby appoint the following attorney(s) and/or agent(s) to prosecute this application and transact all business in the Patent and Trademark Office connected therewith (list name and registration number).

The undersigned hereby authorizes any U. S. attorney or agent named herein to accept and follow instructions from _____ as to any action to be taken in the Patent and Trademark Office regarding this application without direct communication between the U. S. attorney or agent and the undersigned. In the event of a change in the persons from whom instructions may be taken, the U. S. attorneys or agents named herein will be so notified by the undersigned.

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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In Re Application of:

Shunpei YAMAZAKI et al

Serial No.: Not Assigned

Filed: Herewith

For: SEMICONDUCTOR DEVICE AND METHOD
OF FABRICATING THEREOF

To:

Commissioner for Patents
Washington D.C. 20231

)
) "Express Mail" Mailing Label No. EL613563973

) Date of Deposit April 24, 2001

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Name Ruben M. Gamez
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Signature Ruben M. Gamez

APPOINTMENT OF ASSOCIATE ATTORNEYS

Sir:

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the above captioned application:

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